

## 10-MHz LOW-NOISE LOW-VOLTAGE LOW-POWER OPERATIONAL AMPLIFIERS

Check for Samples: [LMV721](#), [LMV722](#)

### FEATURES

- Power-Supply Voltage Range: 2.2 V to 5.5 V
- Low Supply Current: 930  $\mu$ A/Amplifier at 2.2 V
- High Unity-Gain Bandwidth: 10 MHz
- Rail-to-Rail Output Swing
  - 600- $\Omega$  Load: 120 mV From Either Rail at 2.2 V
  - 2-k $\Omega$  Load: 50 mV From Either Rail at 2.2 V
- Input Common-Mode Voltage Range Includes Ground
- Input Voltage Noise: 9 nV/ $\sqrt{\text{Hz}}$  at f = 1 kHz

### APPLICATIONS

- Cellular and Cordless Phones
- Active Filter and Buffers
- Laptops and PDAs
- Battery Powered Electronics

### DESCRIPTION/ORDERING INFORMATION

The LMV721 (single) and LMV722 (dual) are low-noise low-voltage low-power operational amplifiers that can be designed into a wide range of applications. The LMV721 and LMV722 have a unity-gain bandwidth of 10 MHz, a slew rate of 5 V/ $\mu$ s, and a quiescent current of 930  $\mu$ A/amplifier at 2.2 V.

The LMV721 and LMV722 are designed to provide optimal performance in low-voltage and low-noise systems. They provide rail-to-rail output swing into heavy loads. The input common-mode voltage range includes ground, and the maximum input offset voltage are 3.5 mV (over recommended temperature range) for the devices. Their capacitive load capability is also good at low supply voltages. The operating range is from 2.2 V to 5.5 V.

#### ORDERING INFORMATION<sup>(1)</sup>

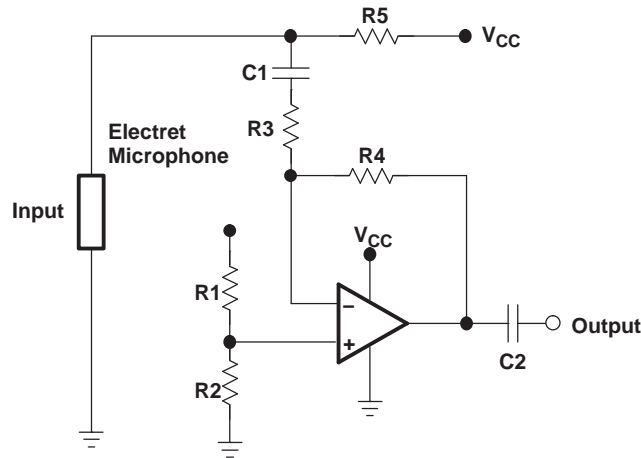
T <sub>A</sub>	PACKAGE <sup>(2)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING <sup>(3)</sup>	
–40°C to 105°C	Single	SC-70 – DCK	Reel of 3000	LMV721DCKR	RK_
			Reel of 250	LMV721DCKT	
		SOT-23 – DBV	Reel of 3000	LMV721DBVR	RBF_
	Dual	SOIC – D	Reel of 2500	LMV722IDR	MV722I
			Tube of 75	LMV722ID	
		VSSOP – DGK	Reel of 2500	LMV722IDGKR	R6_
	QFN – DRG	Reel of 2500	LMV722IDRGR	ZYY	

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at [www.ti.com](http://www.ti.com).
- (2) Package drawings, thermal data, and symbolization are available at [www.ti.com/packaging](http://www.ti.com/packaging).
- (3) DBV/DCK/DGK: The actual top-side marking has one additional character that designates the wafer fab/assembly site.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

## Typical Application



## Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
$V_{CC+} - V_{CC-}$	Supply voltage <sup>(2)</sup>		6	V
$V_{ID}$	Differential input voltage <sup>(3)</sup>	±Supply voltage		V
$\theta_{JA}$	Package thermal impedance <sup>(4)</sup>	D package <sup>(5)</sup>		°C/W
		DBV package <sup>(5)</sup>		
		DCK package <sup>(5)</sup>		
		DGK package <sup>(5)</sup>		
		DRG package <sup>(6)</sup>		
$T_J$	Operating virtual-junction temperature		150	°C
$T_{stg}$	Storage temperature range	-65	150	°C

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values (except differential voltages and  $V_{CC}$  specified for the measurement of  $I_{OS}$ ) are with respect to the network GND.
- (3) Differential voltages are at IN+ with respect to IN-.
- (4) Maximum power dissipation is a function of  $T_J(\max)$ ,  $\theta_{JA}$ , and  $T_A$ . The maximum allowable power dissipation at any allowable ambient temperature is  $P_D = (T_J(\max) - T_A)/\theta_{JA}$ . Operating at the absolute maximum  $T_J$  of 150°C can affect reliability.
- (5) The package thermal impedance is calculated in accordance with JESD 51-7.
- (6) The package thermal impedance is calculated in accordance with JESD 51-5.

## Recommended Operating Conditions

		MIN	MAX	UNIT
$V_{CC+} - V_{CC-}$	Supply voltage	2.2	5.5	V
$T_J$	Operating virtual-junction temperature	-40	105	°C

## ESD Protection

	TYP	UNIT
Human-Body Model	2000	V
Machine Model	100	V

## Electrical Characteristics

 $V_{CC+} = 2.2\text{ V}$ ,  $V_{CC-} = \text{GND}$ ,  $V_{ICR} = V_{CC+}/2$ ,  $V_O = V_{CC+}/2$ , and  $R_L > 1\text{ M}\Omega$  (unless otherwise noted)

PARAMETER		TEST CONDITIONS	$T_J$	MIN	TYP	MAX	UNIT	
$V_{IO}$	Input offset voltage		25°C		0.02	3	mV	
			–40°C to 105°C			3.5		
$TCV_{IO}$	Input offset voltage average drift		25°C		0.6		$\mu\text{V}/^\circ\text{C}$	
$I_{IB}$	Input bias current		25°C		260		nA	
$I_{IO}$	Input offset current		25°C		25		nA	
CMMR	Common-mode rejection ratio	$V_{ICR} = 0\text{ V to }1.3\text{ V}$	25°C	70	88		dB	
			–40°C to 105°C	64				
PSRR	Power-supply rejection ratio	$V_{CC+} = 2.2\text{ V to }5\text{ V}$ , $V_O = 0$ , $V_{ICR} = 0$	25°C	80	90		dB	
			–40°C to 105°C	70				
$V_{ICR}$	Input common-mode voltage	CMRR $\geq 50\text{ dB}$	25°C		–0.3		V	
					1.3			
$A_{VD}$	Large-signal voltage gain	$R_L = 600\ \Omega$ , $V_O = 0.75\text{ V to }2\text{ V}$	25°C	75	81		dB	
			–40°C to 105°C	70				
		$R_L = 2\text{ k}\Omega$ , $V_O = 0.5\text{ V to }2.1\text{ V}$	25°C	75	84			
			–40°C to 105°C	70				
$V_O$	Output swing	$R_L = 600\ \Omega\text{ to }V_{CC+}/2$	25°C	2.090	2.125		V	
			–40°C to 105°C	2.065				
			25°C		0.071	0.120		
			–40°C to 105°C			0.145		
		$R_L = 2\text{ k}\Omega\text{ to }V_{CC+}/2$	25°C	2.150	2.177			
			–40°C to 105°C	2.125				
			25°C		0.056	0.080		
			–40°C to 105°C			0.105		
$I_O$	Output current	Sourcing, $V_O = 0\text{ V}$ , $V_{IN(\text{diff})} = \pm 0.5\text{ V}$	25°C	10	14.9		mA	
			–40°C to 105°C	5				
		Sinking, $V_O = 2.2\text{ V}$ , $V_{IN(\text{diff})} = \pm 0.5\text{ V}$	25°C	10	17.6			
			–40°C to 105°C	5				
$I_{CC}$	Supply current	LMV721	25°C		0.93	1.3	mA	
			–40°C to 105°C			1.5		
		LMV722	25°C		1.81	2.4		
			–40°C to 105°C			2.6		
SR	Slew rate <sup>(1)</sup>		25°C		4.9		V/ $\mu\text{s}$	
GBW	Gain bandwidth product		25°C		10		MHz	
$\Phi_m$	Phase margin		25°C		67.4		°	
$G_m$	Gain margin		25°C		–9.8		dB	
$V_n$	Input-referred voltage noise	$f = 1\text{ kHz}$	25°C		9		$\text{nV}/\sqrt{\text{Hz}}$	
$I_n$	Input-referred current noise	$f = 1\text{ kHz}$	25°C		0.3		$\text{pA}/\sqrt{\text{Hz}}$	
THD	Total harmonic distortion	$f = 1\text{ kHz}$ , $A_V = 1$ , $R_L = 600\ \Omega$ , $V_O = 500\text{ mV}_{pp}$	25°C		0.004		%	

(1) Connected as voltage follower with 1-V step input. Number specified is the slower of the positive and negative slew rate.

### Electrical Characteristics

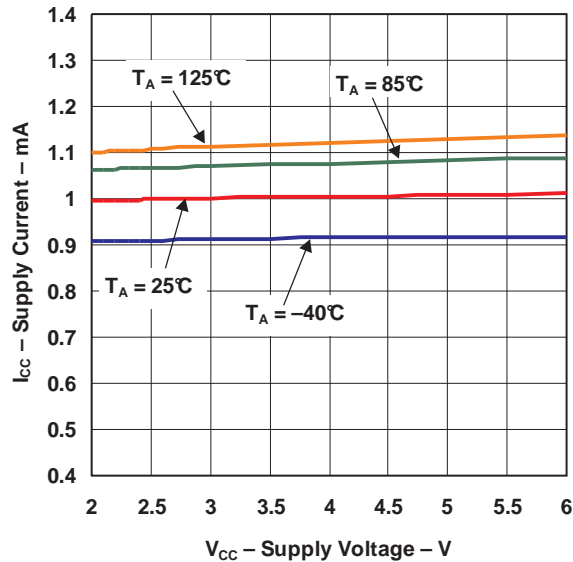
$V_{CC+} = 5\text{ V}$ ,  $V_{CC-} = \text{GND}$ ,  $V_{ICR} = V_{CC+}/2$ ,  $V_O = V_{CC+}/2$ , and  $R_L > 1\text{ M}\Omega$  (unless otherwise noted)

PARAMETER		TEST CONDITIONS	$T_J$	MIN	TYP	MAX	UNIT
$V_{IO}$	Input offset voltage		25°C	-0.08	3		mV
			-40°C to 105°C			3.5	
$TCV_{IO}$	Input offset voltage average drift		25°C	0.6			$\mu\text{V}/^\circ\text{C}$
$I_{IB}$	Input bias current		25°C	260			nA
$I_{IO}$	Input offset current		25°C	25			nA
CMMR	Common-mode rejection ratio	$V_{ICR} = 0\text{ V to } 4.1\text{ V}$	25°C	80	89		dB
			-40°C to 105°C	75			
PSRR	Power-supply rejection ratio	$V_{CC+} = 2.2\text{ V to } 5\text{ V}$ , $V_O = 0$ , $V_{ICR} = 0$	25°C	70	90		dB
			-40°C to 105°C	64			
$V_{ICR}$	Input common-mode voltage	CMRR $\geq 50\text{ dB}$	25°C	-0.3			V
				4.1			
$A_{VD}$	Large-signal voltage gain	$R_L = 600\ \Omega$ , $V_O = 0.75\text{ V to } 4.8\text{ V}$	25°C	80	87		dB
			-40°C to 105°C	70			
		$R_L = 2\text{ k}\Omega$ , $V_O = 0.7\text{ V to } 4.9\text{ V}$	25°C	80	94		
			-40°C to 105°C	70			
$V_O$	Output swing	$R_L = 600\ \Omega\text{ to } V_{CC+}/2$	25°C	4.84	4.882		V
			-40°C to 105°C	4.815			
			25°C	0.134	0.19		
			-40°C to 105°C	0.215			
		$R_L = 2\text{ k}\Omega\text{ to } V_{CC+}/2$	25°C	4.93	4.952		
			-40°C to 105°C	4.905			
			25°C	0.076	0.11		
			-40°C to 105°C	0.135			
$I_O$	Output current	Sourcing, $V_O = 0\text{ V}$ , $V_{IN(\text{diff})} = \pm 0.5\text{ V}$	25°C	20	52.6		mA
			-40°C to 105°C	12			
		Sinking, $V_O = 2.2\text{ V}$ , $V_{IN(\text{diff})} = \pm 0.5\text{ V}$	25°C	15	23.7		
			-40°C to 105°C	8.5			
$I_{CC}$	Supply current	LMV721	25°C	1.03	1.4		mA
			-40°C to 105°C			1.7	
		LMV722	25°C	2.01	2.4		
			-40°C to 105°C			2.8	
SR	Slew rate <sup>(1)</sup>		25°C	5.25			V/ $\mu\text{s}$
GBW	Gain bandwidth product		25°C	10			MHz
$\Phi_m$	Phase margin		25°C	72			°
$G_m$	Gain margin		25°C	-11			dB
$V_n$	Input-referred voltage noise	$f = 1\text{ kHz}$	25°C	8.5			$\text{nV}/\sqrt{\text{Hz}}$
$I_n$	Input-referred current noise	$f = 1\text{ kHz}$	25°C	0.2			$\text{pA}/\sqrt{\text{Hz}}$
THD	Total harmonic distortion	$f = 1\text{ kHz}$ , $AV = 1$ , $R_L = 600\ \Omega$ , $V_O = 500\text{ mV}_{pp}$	25°C	0.001			%

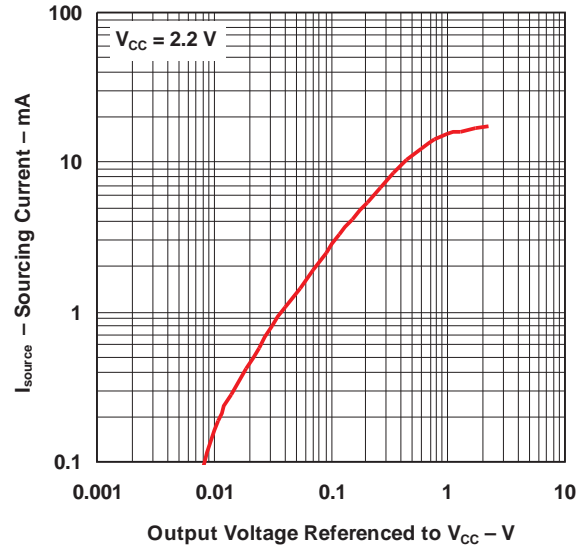
(1) Connected as voltage follower with 1-V step input. Number specified is the slower of the positive and negative slew rate.

TYPICAL CHARACTERISTICS

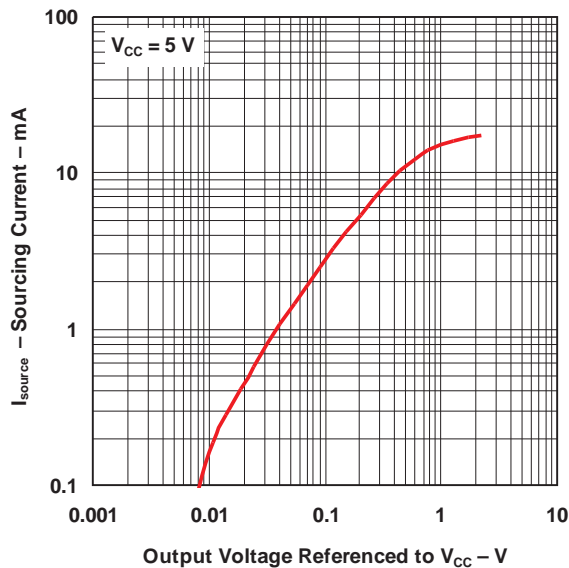
SUPPLY CURRENT  
vs  
SUPPLY VOLTAGE



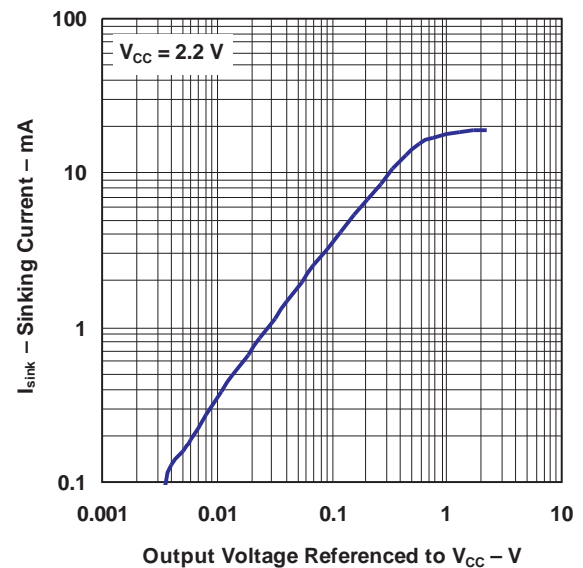
SOURCING CURRENT  
vs  
OUTPUT VOLTAGE



SOURCING CURRENT  
vs  
OUTPUT VOLTAGE

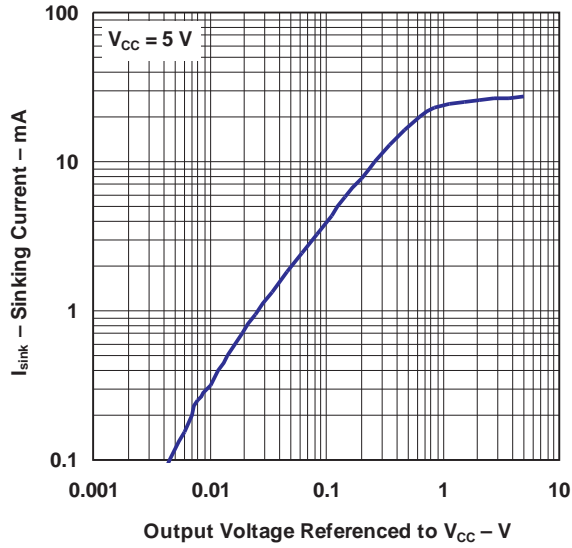


SINKING CURRENT  
vs  
OUTPUT VOLTAGE

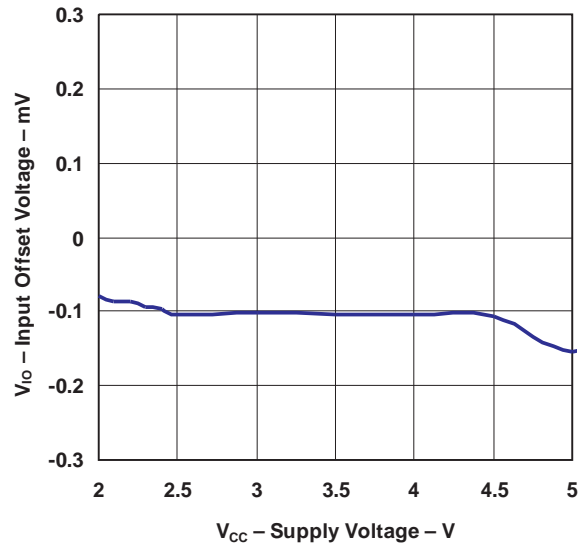


**TYPICAL CHARACTERISTICS (continued)**

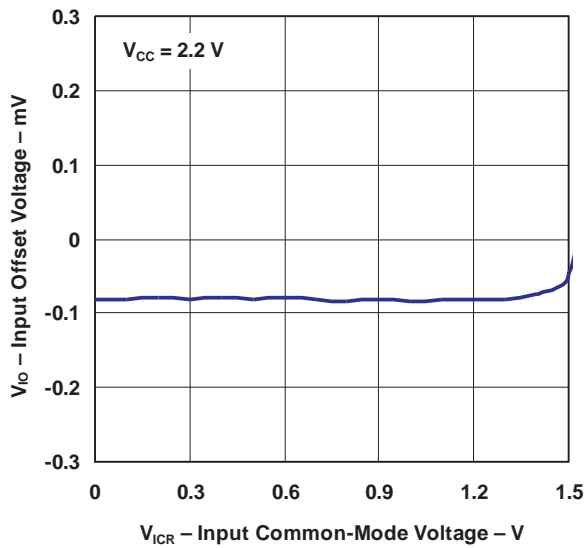
**SINKING CURRENT  
vs  
OUTPUT VOLTAGE**



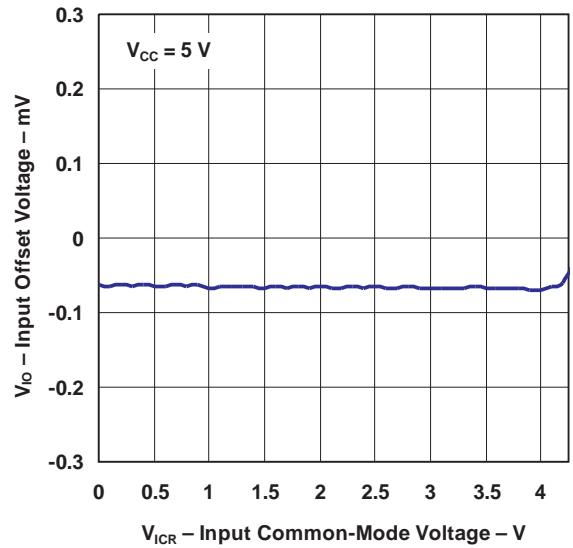
**OUTPUT VOLTAGE SWING  
vs  
SUPPLY VOLTAGE**



**INPUT OFFSET VOLTAGE  
vs  
INPUT COMMON-MODE VOLTAGE**

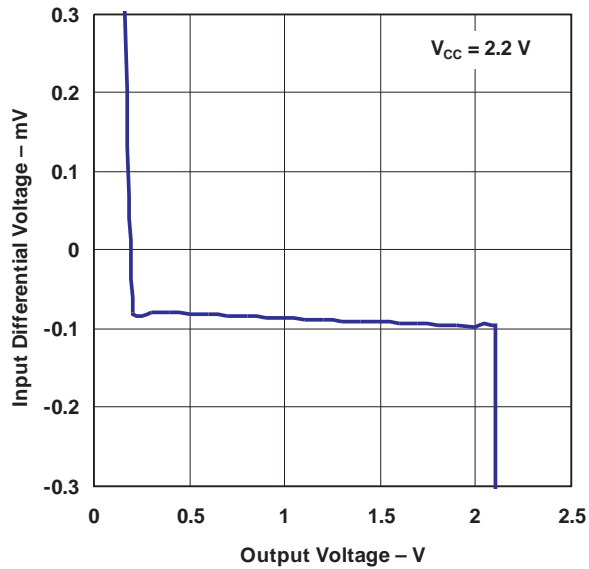


**INPUT OFFSET VOLTAGE  
vs  
INPUT COMMON-MODE VOLTAGE**

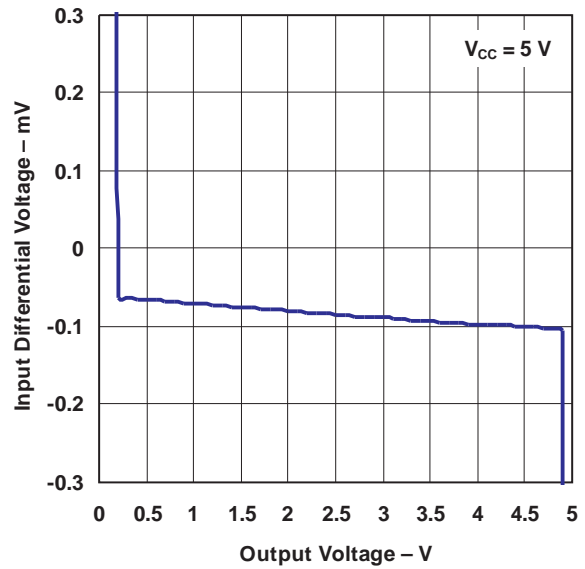


TYPICAL CHARACTERISTICS (continued)

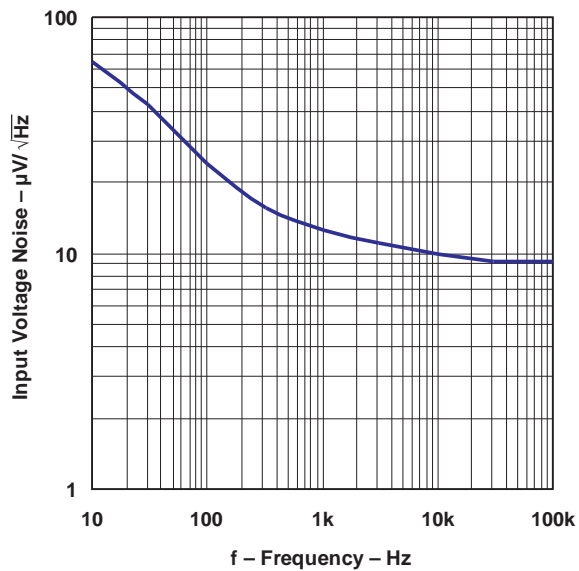
INPUT VOLTAGE  
vs  
OUTPUT VOLTAGE



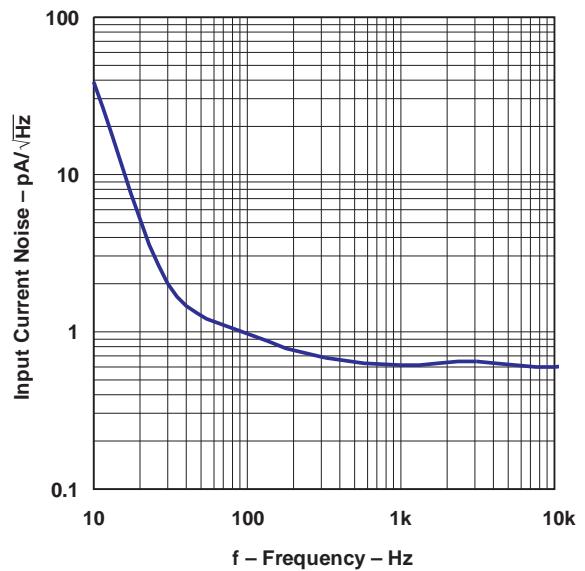
INPUT VOLTAGE  
vs  
OUTPUT VOLTAGE



INPUT VOLTAGE NOISE  
vs  
FREQUENCY

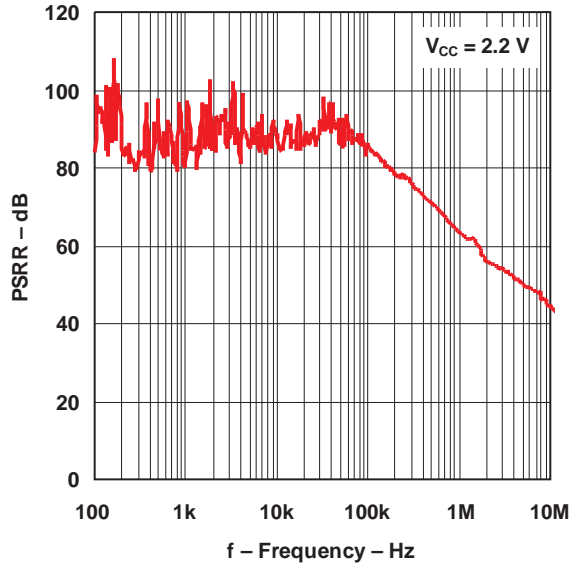


INPUT CURRENT NOISE  
vs  
FREQUENCY

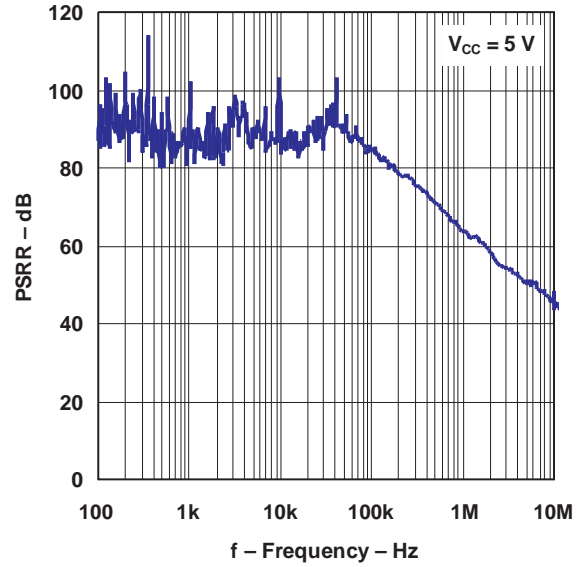


**TYPICAL CHARACTERISTICS (continued)**

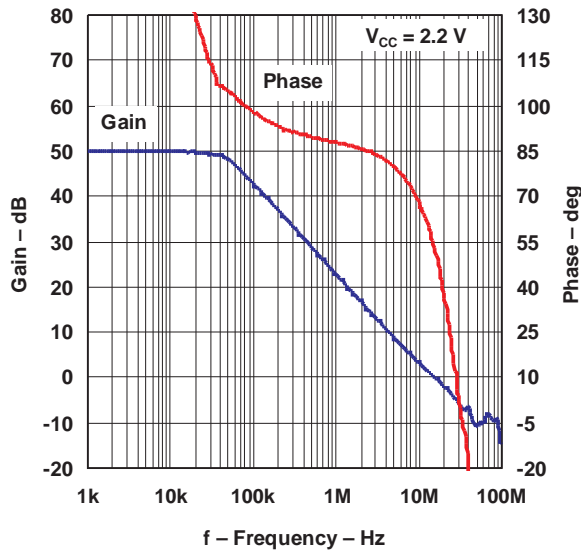
**PSRR  
vs  
FREQUENCY**



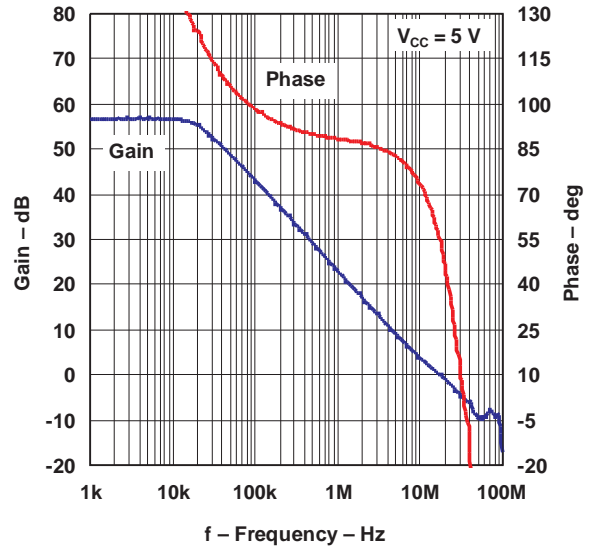
**PSRR  
vs  
FREQUENCY**



**GAIN AND PHASE  
vs  
FREQUENCY**

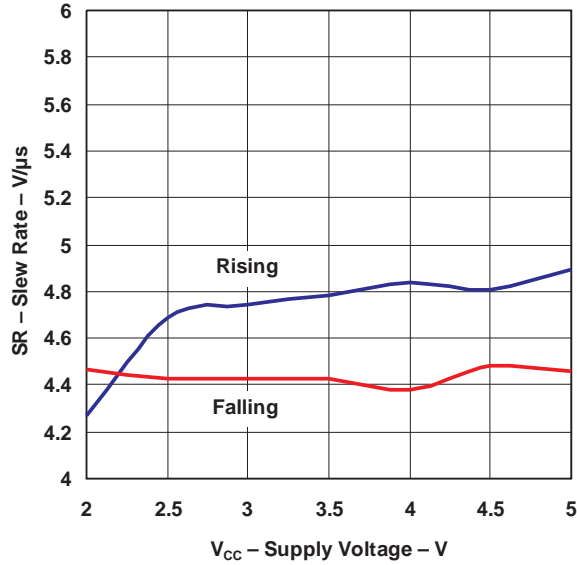


**GAIN AND PHASE  
vs  
FREQUENCY**

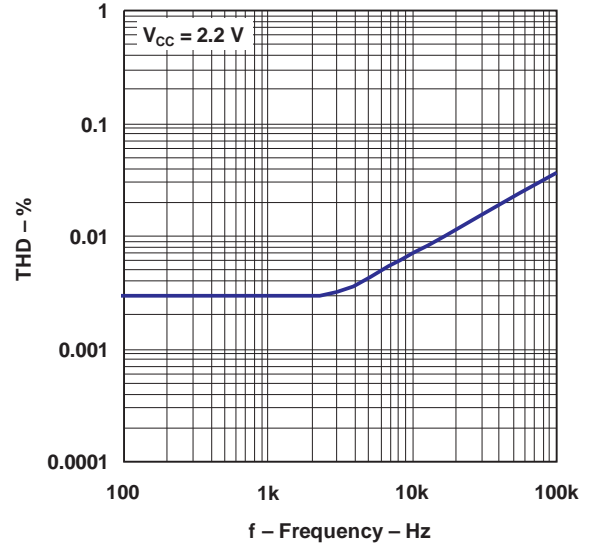


TYPICAL CHARACTERISTICS (continued)

SLEW RATE  
vs  
SUPPLY VOLTAGE

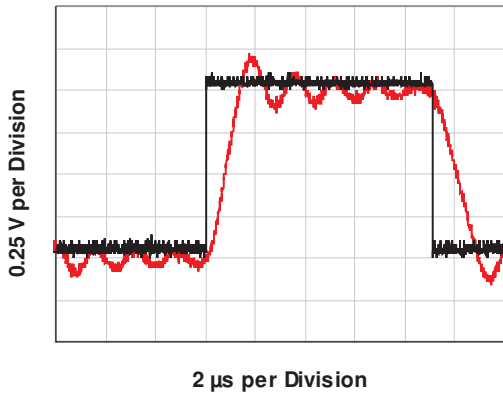


THD  
vs  
FREQUENCY



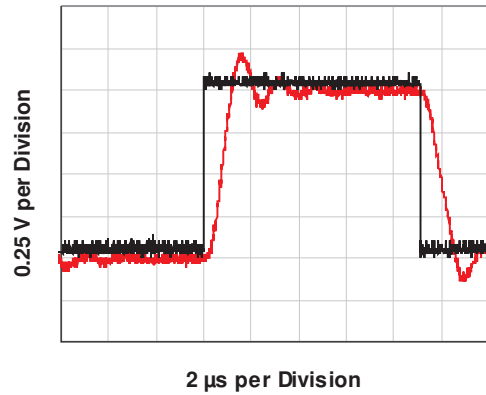
PULSE RESPONSE

V<sub>CC</sub> = 5 V, R<sub>L</sub> = 2 kΩ, C<sub>L</sub> = 21.2 nF, R<sub>O</sub> = 0 Ω



PULSE RESPONSE

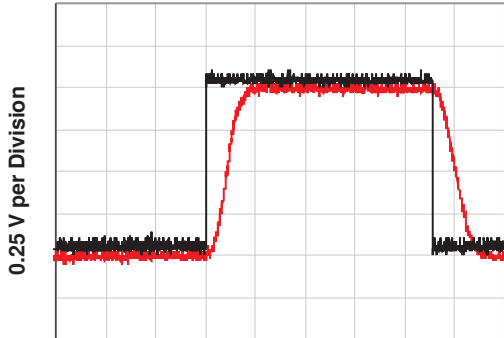
V<sub>CC</sub> = 5 V, R<sub>L</sub> = 2 kΩ, C<sub>L</sub> = 21.2 nF, R<sub>O</sub> = 2.1 Ω



**TYPICAL CHARACTERISTICS (continued)**

**PULSE RESPONSE**

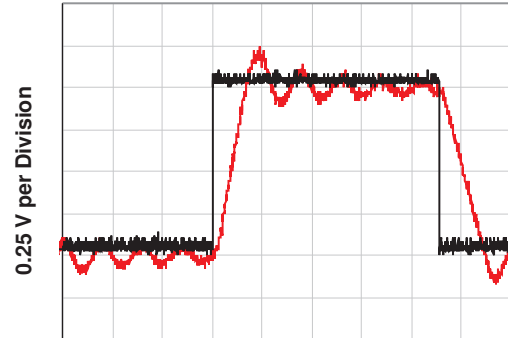
$V_{cc} = 5\text{ V}, R_L = 2\text{ k}\Omega, C_L = 21.2\text{ nF}, R_o = 9.5\ \Omega$



2  $\mu\text{s}$  per Division

**PULSE RESPONSE**

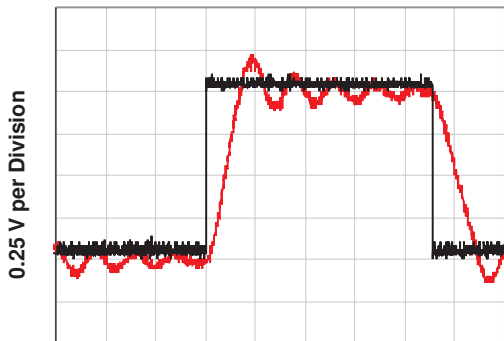
$V_{cc} = 5\text{ V}, R_L = 10\text{ k}\Omega, C_L = 21.2\text{ nF}, R_o = 0\ \Omega$



2  $\mu\text{s}$  per Division

**PULSE RESPONSE**

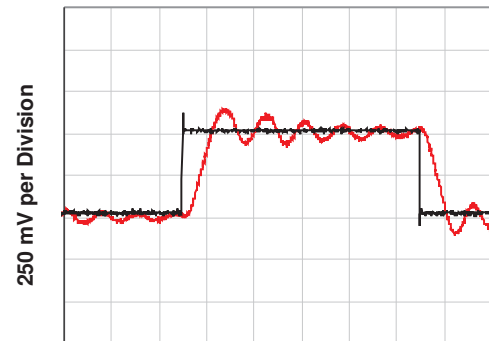
$V_{cc} = 5\text{ V}, R_L = 600\ \Omega, C_L = 21.2\text{ nF}, R_o = 0\ \Omega$



2  $\mu\text{s}$  per Division

**PULSE RESPONSE**

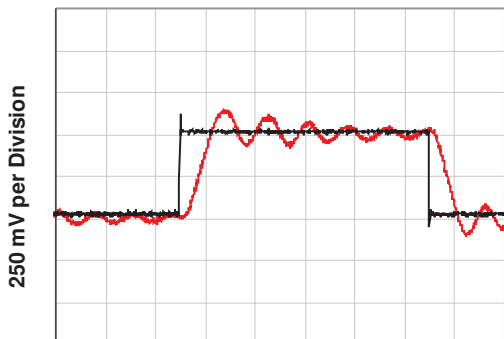
$V_{cc} = 2.2\text{ V}, R_L = 2\ \Omega, C_L = 2.12\text{ nF}, R_o = 0\ \Omega$



1  $\mu\text{s}$  per Division

**PULSE RESPONSE**

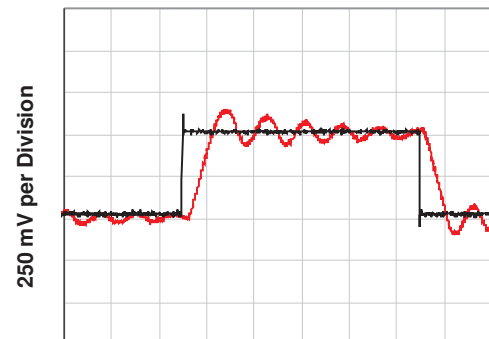
$V_{cc} = 2.2\text{ V}, R_L = 2\text{ k}\Omega, C_L = 2.12\text{ nF}, R_o = 0\ \Omega$



1  $\mu\text{s}$  per Division

**PULSE RESPONSE**

$V_{cc} = 2.2\text{ V}, R_L = 10\text{ k}\Omega, C_L = 2.12\text{ nF}, R_o = 0\ \Omega$

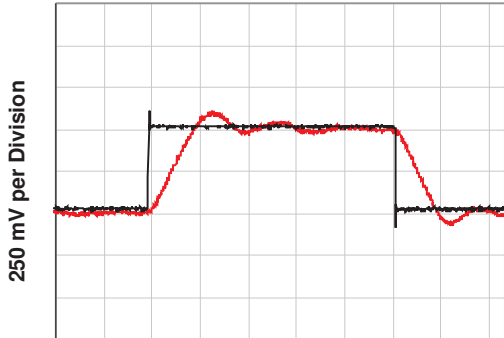


1  $\mu\text{s}$  per Division

**TYPICAL CHARACTERISTICS (continued)**

**PULSE RESPONSE**

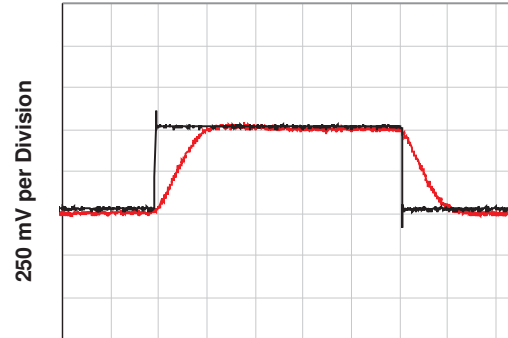
$V_{CC} = 2.2\text{ V}$ ,  $R_L = 10\text{ k}\Omega$ ,  $C_L = 2.12\text{ nF}$ ,  $R_o = 2.2\ \Omega$



1  $\mu\text{s}$  per Division

**PULSE RESPONSE**

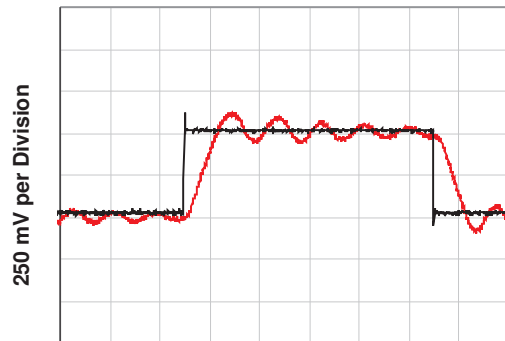
$V_{CC} = 2.2\text{ V}$ ,  $R_L = 10\text{ k}\Omega$ ,  $C_L = 2.12\text{ nF}$ ,  $R_o = 11.5\ \Omega$



1  $\mu\text{s}$  per Division

**PULSE RESPONSE**

$V_{CC} = 2.2\text{ V}$ ,  $R_L = 600\ \Omega$ ,  $C_L = 1.89\text{ nF}$ ,  $R_o = 0\ \Omega$



1  $\mu\text{s}$  per Division

## REVISION HISTORY

Changes from Revision B (August 2010) to Revision C	Page
• Changed all temperature parameters from max of 85°C to 105°C .....	1
• Changed supply voltage max value to 6 in Absolute Maximum Ratings table .....	2
• Changed supply voltage MAX value to 5.5 in Recommended Operating Conditions table .....	2
• Changed $A_{VD}$ , $V_O$ test conditons for $R_L = 600 \Omega$ : 0.75 V to 4.8 V .....	4
• Changed $A_{VD}$ , $V_O$ test conditons for $R_L = 2 \text{ k}\Omega$ : 0.75 V to 4.8 V .....	4

**PACKAGING INFORMATION**

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
<a href="#">LMV721IDBVR</a>	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	(RBFA, RBFM)
LMV721IDBVR.A	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	(RBFA, RBFM)
LMV721IDBVRG4	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	RBFM
LMV721IDBVRG4.A	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	RBFM
<a href="#">LMV721IDCKR</a>	Active	Production	SC70 (DCK)   5	3000   LARGE T&R	Yes	NIPDAU   SN   NIPDAUAG	Level-1-260C-UNLIM	-40 to 105	(RKA, RKM)
LMV721IDCKR.A	Active	Production	SC70 (DCK)   5	3000   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 105	(RKA, RKM)
<a href="#">LMV721IDCKT</a>	Active	Production	SC70 (DCK)   5	250   SMALL T&R	Yes	NIPDAU   NIPDAUAG	Level-1-260C-UNLIM	-40 to 105	(RKA, RKM)
LMV721IDCKT.A	Active	Production	SC70 (DCK)   5	250   SMALL T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 105	(RKA, RKM)
<a href="#">LMV722ID</a>	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	MV722I
LMV722ID.A	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	MV722I
<a href="#">LMV722IDGKR</a>	Active	Production	VSSOP (DGK)   8	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	R6E
LMV722IDGKR.A	Active	Production	VSSOP (DGK)   8	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	R6E
<a href="#">LMV722IDR</a>	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	MV722I
LMV722IDR.A	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	MV722I

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

**OTHER QUALIFIED VERSIONS OF LMV722 :**

- Automotive : [LMV722-Q1](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**

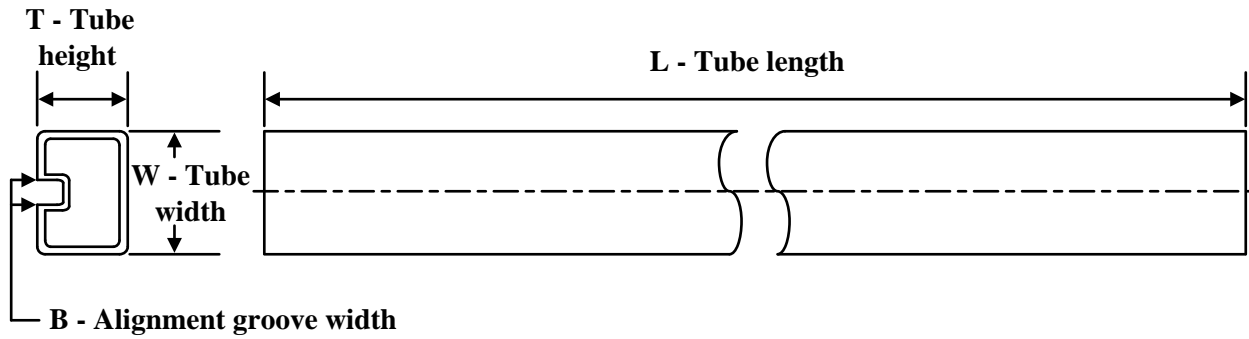

\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMV721IDBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
LMV721IDBVRG4	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
LMV721IDCKR	SC70	DCK	5	3000	178.0	8.4	2.25	2.45	1.2	4.0	8.0	Q3
LMV721IDCKT	SC70	DCK	5	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
LMV721IDCKT	SC70	DCK	5	250	180.0	8.4	2.47	2.3	1.25	4.0	8.0	Q3
LMV722IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.3	1.3	8.0	12.0	Q1
LMV722IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMV721IDBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
LMV721IDBVRG4	SOT-23	DBV	5	3000	180.0	180.0	18.0
LMV721IDCKR	SC70	DCK	5	3000	208.0	191.0	35.0
LMV721IDCKT	SC70	DCK	5	250	180.0	180.0	18.0
LMV721IDCKT	SC70	DCK	5	250	202.0	201.0	28.0
LMV722IDGKR	VSSOP	DGK	8	2500	346.0	346.0	35.0
LMV722IDR	SOIC	D	8	2500	353.0	353.0	32.0

**TUBE**


\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
LMV722ID	D	SOIC	8	75	507	8	3940	4.32
LMV722ID.A	D	SOIC	8	75	507	8	3940	4.32



# EXAMPLE BOARD LAYOUT

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:15X



SOLDER MASK DETAILS

4214839/K 08/2024

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



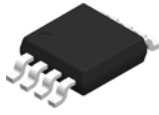
SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:15X

4214839/K 08/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

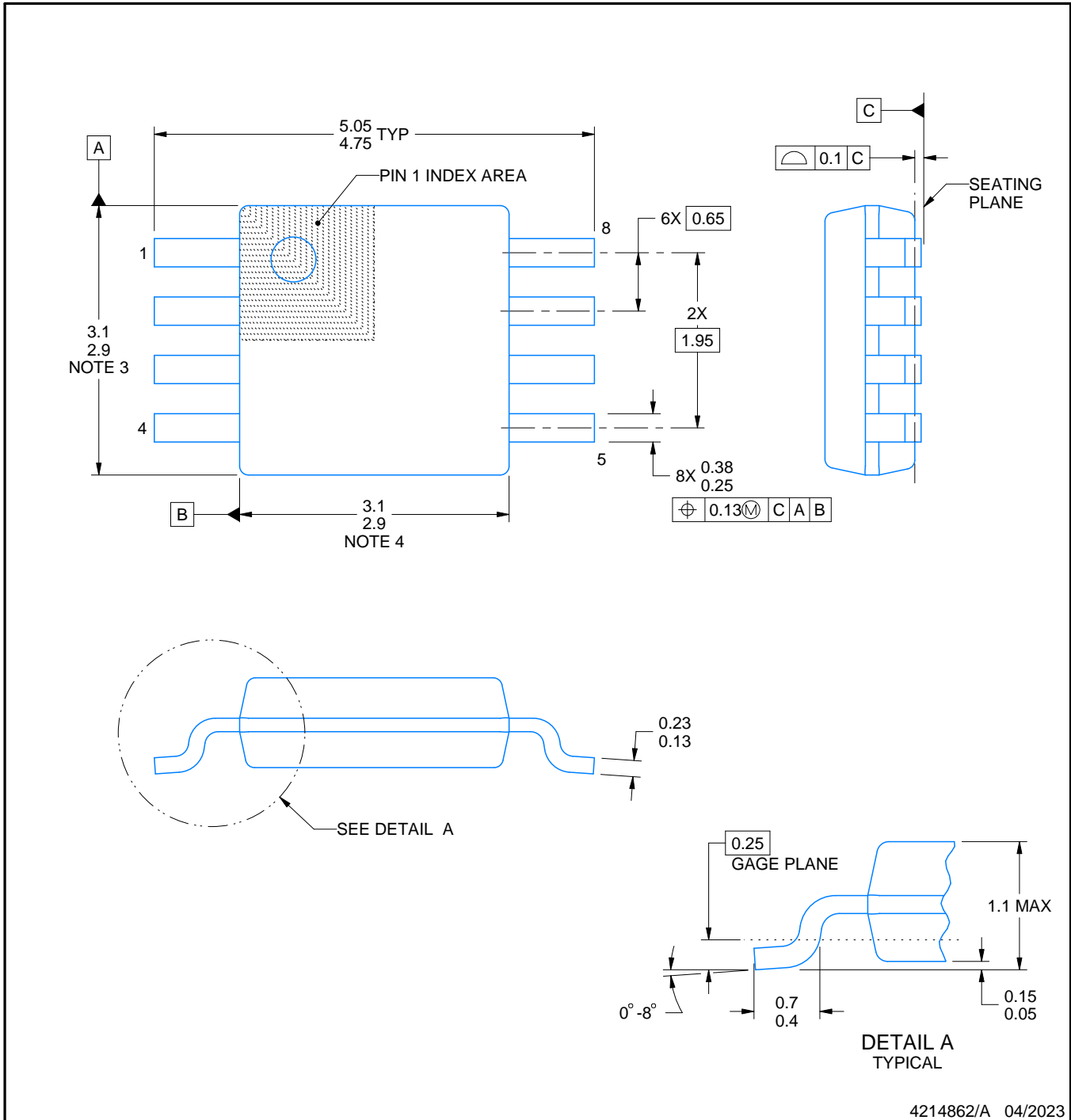
# DGK0008A



# PACKAGE OUTLINE

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



4214862/A 04/2023

**NOTES:**

PowerPAD is a trademark of Texas Instruments.

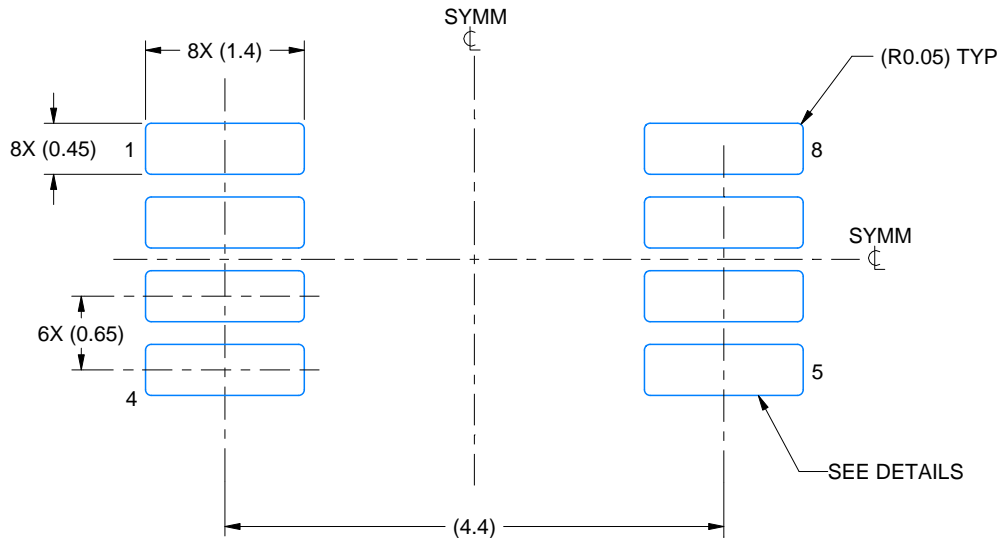
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

# EXAMPLE BOARD LAYOUT

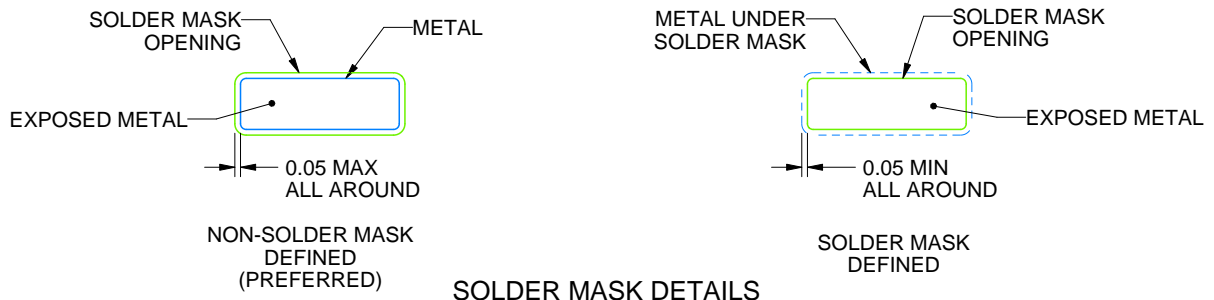
DGK0008A

™ VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 15X



SOLDER MASK DETAILS

4214862/A 04/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

# EXAMPLE STENCIL DESIGN

DGK0008A

™ VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE  
SCALE: 15X

4214862/A 04/2023

NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

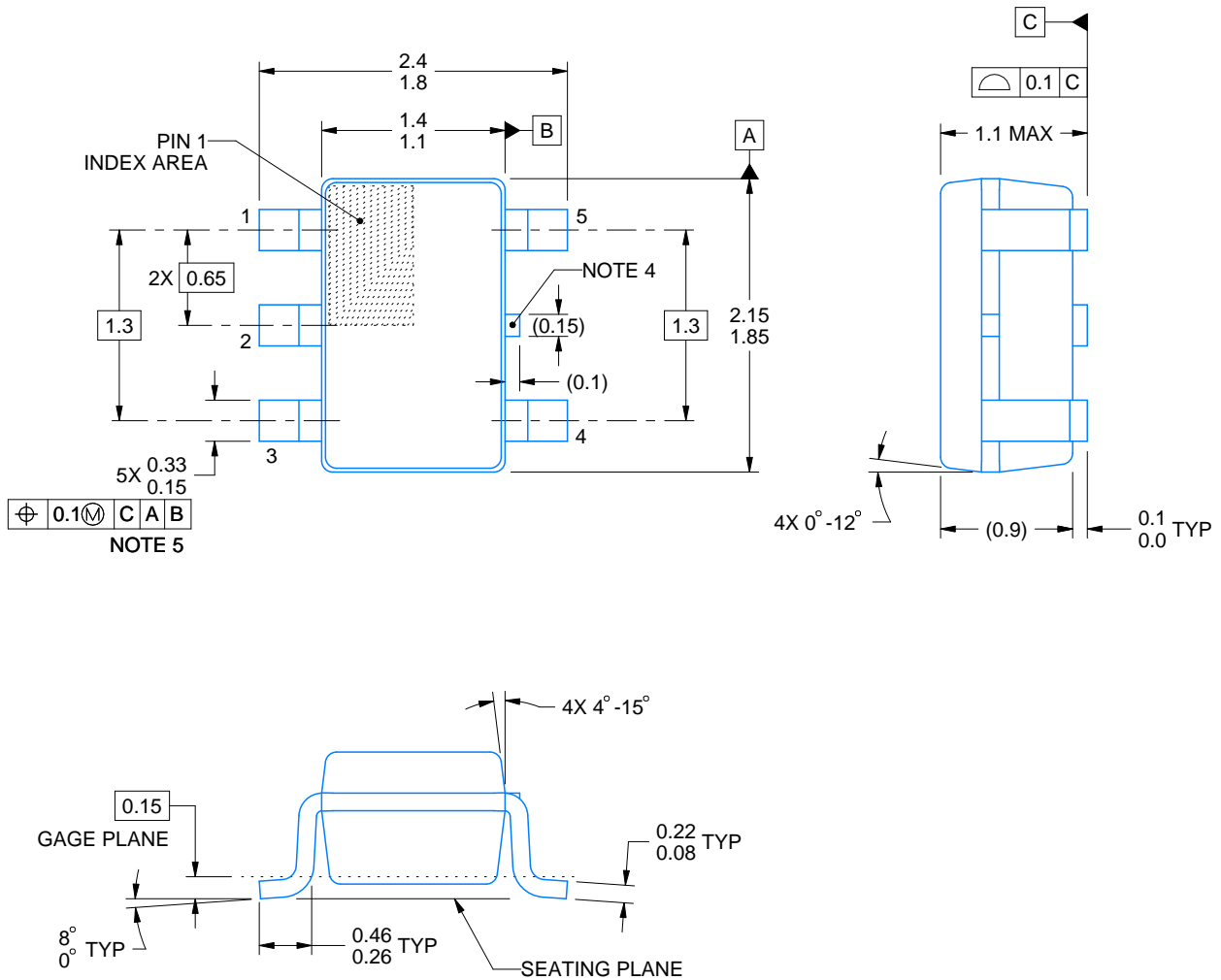
# DCK0005A



## PACKAGE OUTLINE

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



4214834/G 11/2024

### NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-203.
4. Support pin may differ or may not be present.
5. Lead width does not comply with JEDEC.
6. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side

# EXAMPLE BOARD LAYOUT

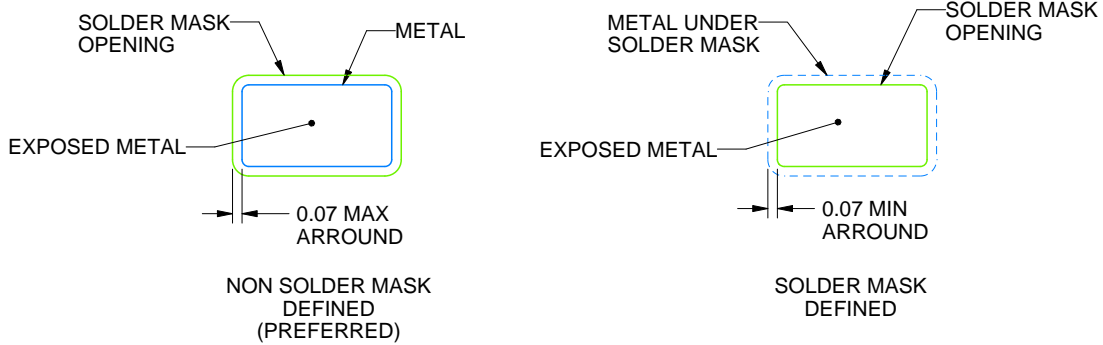
DCK0005A

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:18X



SOLDER MASK DETAILS

4214834/G 11/2024

NOTES: (continued)

- 7. Publication IPC-7351 may have alternate designs.
- 8. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

DCK0005A

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE  
BASED ON 0.125 THICK STENCIL  
SCALE: 18X

4214834/G 11/2024

NOTES: (continued)

9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
10. Board assembly site may have different recommendations for stencil design.



D0008A

# PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

# EXAMPLE BOARD LAYOUT

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE  
BASED ON .005 INCH [0.125 MM] THICK STENCIL  
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

## IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you fully indemnify TI and its representatives against any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to [TI's Terms of Sale](#), [TI's General Quality Guidelines](#), or other applicable terms available either on [ti.com](http://ti.com) or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products. Unless TI explicitly designates a product as custom or customer-specified, TI products are standard, catalog, general purpose devices.

TI objects to and rejects any additional or different terms you may propose.

Copyright © 2026, Texas Instruments Incorporated

Last updated 10/2025